

# COMMON EMITTER AMPLIFIER DESIGN TIPS & SHORTCUTS

W2AEW

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## CLASS A OPERATION

- USUALLY START WITH GOALS & CONSTRAINTS

- DESIRED GAIN

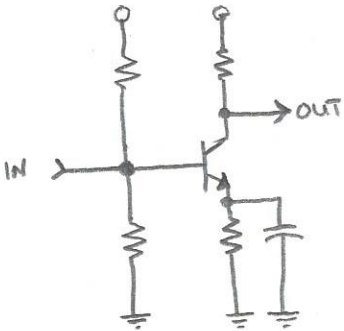
- INPUT / OUTPUT / LOAD RESISTANCES

- INPUT / OUTPUT SIGNAL LEVELS

- POWER SUPPLY VOLTAGE

- POWER DISSIPATION

- MORE...



- RELATED VIDEOS:

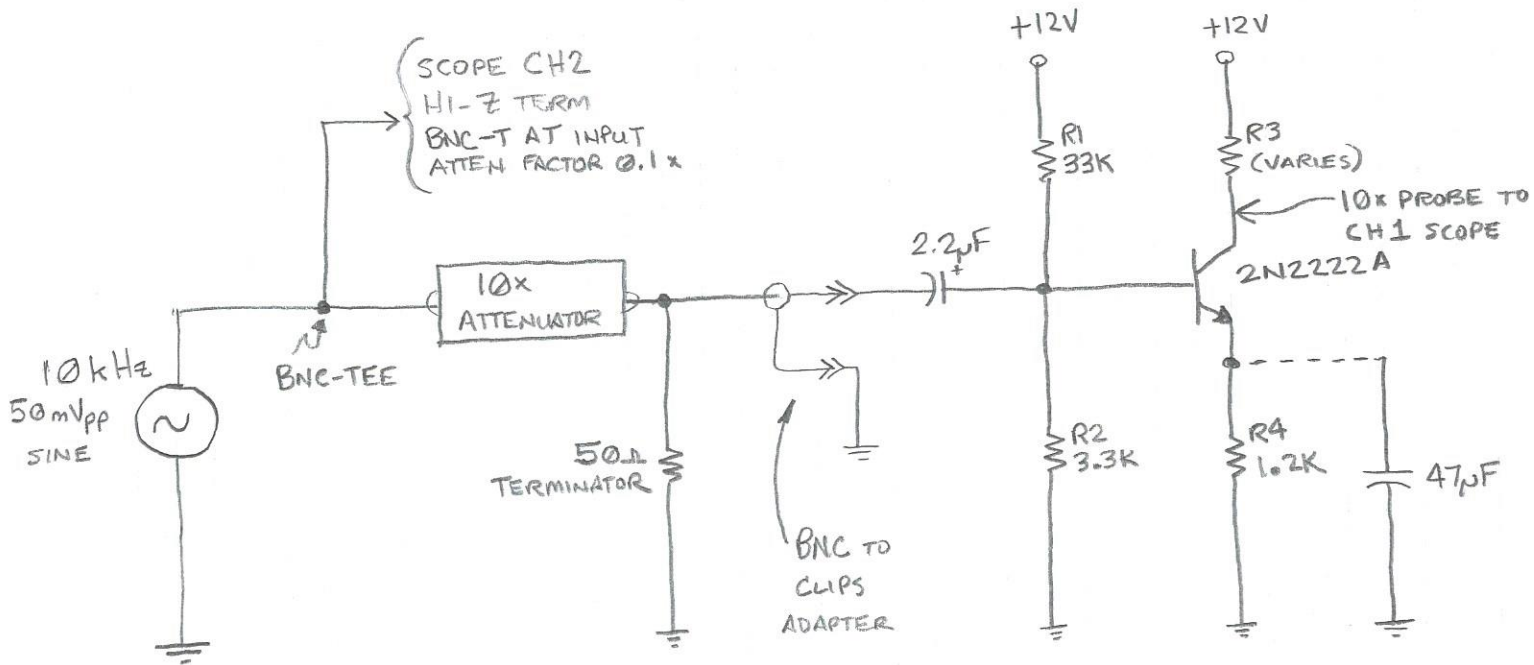
# 185: BIPOLAR TRANSISTOR BIAS CIRCUITS & BETA DEPENDENCE

# 114: COMMON EMITTER / BASE / COLLECTOR AMPLIFIERS

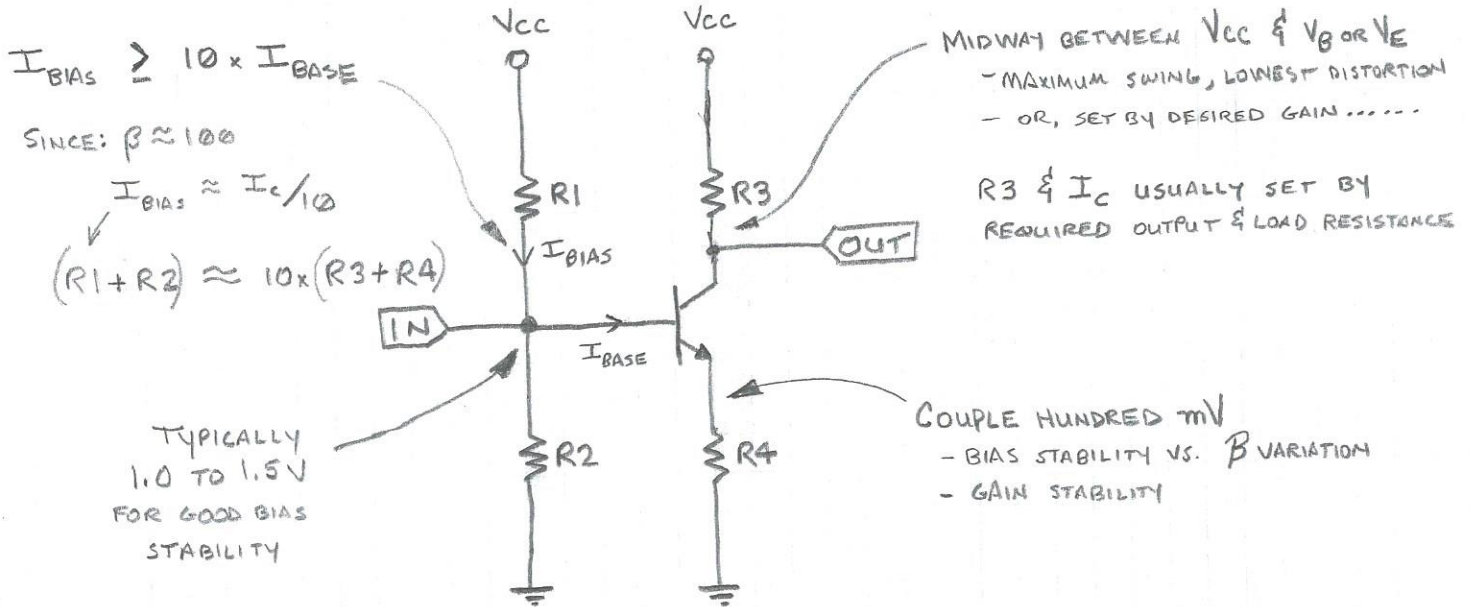
# 113: TRANSISTOR BIAS POINT & CLASS OF OPERATION

# 67: COMMON EMITTER AMP GAIN & FREQ. RESPONSE

TEST CIRCUIT

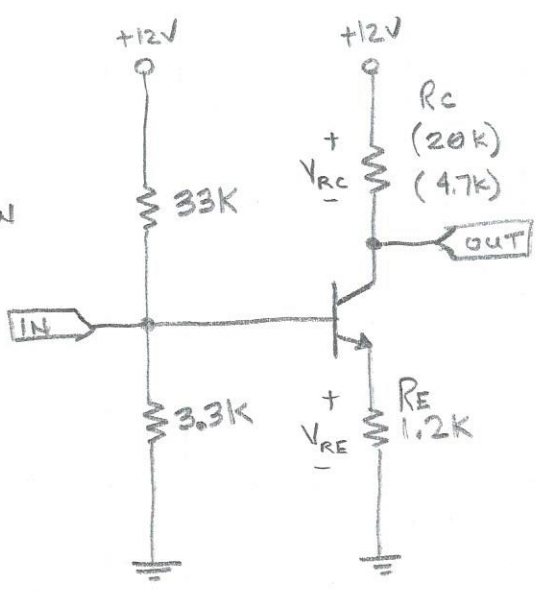


DC BIAS POINT CONSIDERATIONS



GAIN CALCULATIONS

- LOW GAIN
- LOW DISTORTION

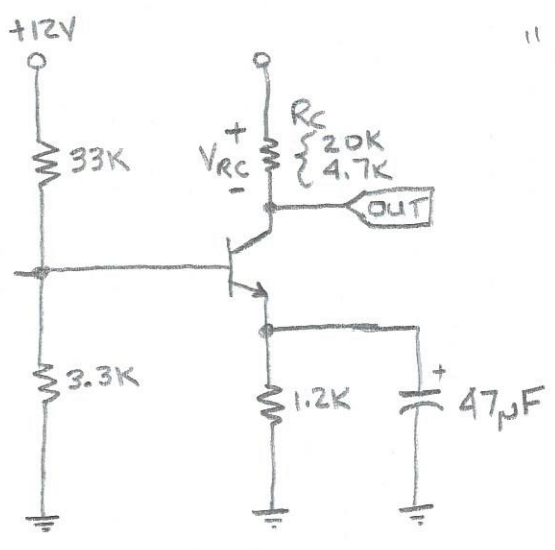


"WITH EMITTER DEGENERATION"

- WITH FEW HUNDRED mV AT EMITTER
- IGNORE INCREMENTAL EMITTER RESISTANCE  $r_e = 1/g_m = V_T/I_C$
- SINCE:  $I_C \approx I_E$
- ANY CHANGE IN  $I_E \approx \Delta I_C$
- THUS,  $A_V \approx - \frac{V_{RC}}{V_{RE}}$

$$A_V \approx - \frac{R_C}{R_E}$$

- HIGH GAIN
- MORE DISTORTION



"WITH EMITTER BYPASSED"

- CAPACITOR SHORTS DEGENERATION AT SIGNAL FREQUENCIES
- EBERS-MOLL APPROXIMATE GAIN EQUATION

$$A_V \approx -g_m \cdot R_C$$

WHERE:  $g_m = \frac{I_C}{V_T}$

$V_T = 26mV @ \text{ROOM TEMP}$

ALSO  $r_e = \frac{1}{g_m} = \frac{V_T}{I_C}$

$$A_V = \frac{R_C}{r_e} \text{ (SAME AS ABOVE)}$$

SUPER SIMPLE SHORTCUT

$$A_V \approx - \frac{V_{RC}}{V_T}$$

ACCURATE  $\approx 10\%$  FOR SMALL SIGNALS ( $\Delta V_{BE} < 10mV$ )

$$\begin{aligned} A_V &= g_m \cdot R_C \\ &= \frac{I_C}{V_T} \cdot R_C \\ &= \frac{1}{V_T} \cdot (I_C \cdot R_C) \\ &= \frac{V_{RC}}{V_T} \end{aligned}$$